



International Workshop on



Advanced Patterning Solutions

The 4th International Workshop on Advanced Patterning Solutions

第四届国际先进光刻技术研讨会

November 5-6, 2020, Sichuan Tennis International Hotel, Chengdu, China

2020年11月5日至6日, 四川川投国际酒店, 成都, 中国

Agenda

Program Chairs: Shinji Okazaki, Xiangzhao Wang, Mark Neisser

Registration 注册	
4 Nov. 2020	12:00-22:00 @酒店大厅 The hotel lobby
5-6 Nov. 2020	08:00-17:00 @酒店大厅 The hotel lobby
DAY 1:	
5 Nov., 2020 (Thursday)	
Shuyun Hall 蜀韵厅	
DAY 1-Morning	
08:30-09:00	Opening Ceremony & Welcome Address Chair: Xu Liu, Yayi Wei
Welcome Address	Xu Liu (COS) 主持及介绍领导 Tianchun Ye (IMECAS) Jian Li (Shuangliu District) Shinji Okazaki (Japan)
09:00-10:05	Plenary and DTCO Session Chair: Xiangzhao Wang
	<i>5 minutes Q&A for each talk</i>
09:00-09:35	H. -S. Philip Wong (Stanford University): (KEYNOTE, Online) Materials and Devices for 3D Integrated Circuits
09:35-10:05	Nan Fu (Hisilicon): (INVITED) Patterning process-window aware DTCO for 12nm FinFET technology and fast yield ramp up

10:05-10:30	Group Photo & Coffee Break
10:30-12:00	Computational Lithography Session Chair: Yanxiang Liu
	<i>5 minutes Q&A for each talk</i>
10:30-11:00	Steffen Schulze (Mentor): (INVITED, Online) Providing Predictive Design & Process Insights to Accelerate Yield Ramp with Calibre Fab Solutions
11:00-11:30	Xuelong Shi 时雪龙 (ICRD): (INVITED) Fast and Accurate Machine Learning Inverse Lithography Using Physics Based Feature Maps and Specially Designed DCNN
11:30-12:00	Xiaodong Meng (AMEDAC 全芯制造): (INVITED) The impact of lenses aberration on CD and position for low k1 lithography
12:00-13:30	Lunch
DAY 1-Afternoon	
13:30-15:10	Metrology and Inspection Session I Chair: Xuelong Shi
	<i>5 minutes Q&A for each talk</i>
13:30-14:00	Masami Ikota (Hitachi High-Tech): (INVITED, Online) Electron Beam Metrology for Advanced Patterning
14:00-14:30	Dean Wu 吴振国 (YMTC 长江存储): (INVITED) 3D NAND Dual-Deck OVL measurement and control
14:30-14:50	Junjun Zhang 张君君 (CXMT 长鑫存储): Real time process monitoring using diffraction-based overlay measurements from YieldStar
14:50-15:10	Dongyu Xu (HLMC 华力微电子): CDSEM-Assisted Optical Metrology for Overlay Control
15:10-15:30	Coffee Break
15:30-17:05	Advanced Material Session I

	Chair: Guoqiang Yang 杨国强
	<i>5 minutes Q&A for each talk</i>
15:30-16:05	Joost Frenken (ARCNL): (KEYNOTE, Online) Materials challenges in EUV lithography
16:05-16:35	Laurent PAIN (CEA Tech-Leti): (INVITED, Online) The virtuous circles of the RTOs -- How to support and boost technology developments from materials to integration
16:35-17:05	Fred Brouwer (ARCNL): (INVITED, Online) Photon-induced reactions in hybrid molecular EUV photoresists
17:05-18:30	Poster Session
	Authors should be present at your poster.
18:40-20:30	Banquet 晚宴 (Shuyun Hall 蜀韵厅) for all attendees

<u>Day 2:</u>	
6 Nov., 2020 (Friday) — Parallel Session I, 并行报告会场 I	
Shuyun Hall Part A, 蜀韵厅 A	
DAY 2-Morning	
08:30-10:00	Equipment and Mask Session Chair: Jing Li
	<i>5 minutes Q&A for each talk</i>
08:30-09:00	Masahiro Morita (Nikon): (INVITED, Online) Integrated Solution of Nikon Exposure, Metrology and Inspection
09:00-09:30	Keita SAKAI (Canon Inc.): (INVITED, Online) Nanoimprint Performance Improvements for High Volume Semiconductor Manufacturing
09:30-10:00	Shingo Yoshikawa (DNP): (INVITED, Online) 5nm node's EUV mask process studies using MBMW
10:00-10:20	Coffee Break

10:20-12:10	Mask Optimization Session Chair: Yaobin Feng & Zhiyang Song
	<i>5 minutes Q&A for each talk</i>
10:20-10:50	Andy Chan (Microsoft): (INVITED, Online) Running OPC workload in Azure, what we learned thus far
10:50-11:20	Peng Liu (Synopsys Inc.): (INVITED, Online) Mask Synthesis using Machine Learning Software & Hardware for EUV Lithography
11:20-11:50	Boer Zhu (ASML): (INVITED) Simulation investigation of resolution enhancement techniques (RETs) in low k1 EUV
11:50-12:10	Fei Peng (Wuhan University): Mask Optimization based on artificial desired pattern
12:10-13:30	Lunch
DAY 2-Afternoon	
13:30-15:00	Process and Roadmap Session Session Chair: Weimin Gao
	<i>5 minutes Q&A for each talk</i>
13:30-14:00	Xuedong Fan (HLMC): (INVITED) A novel SEM image based advanced lithography process control providing quick feedback
14:00-14:30	Billy Tang (Cymer): (INVITED) Improving DOF for an Advanced 3D NAND Via Layer using Multi-Focal Imaging
14:30-15:00	Mustafa BADAROGLU (IEEE IRDS More Moore): (INVITED, Online) More Moore roadmap for high-volume manufacturing - IRDS view
15:00-15:20	Coffee Break
15:20-17:00	Equipment Session II Chair: Bob Dong

	<i>5 minutes Q&A for each talk</i>
15:20-15:50	Toshihiro Oga (Gigaphoton Inc.): (INVITED, Online) Imaging performance improvement by spectral performance stability and Optical Pulse Stretching functionality
15:50-16:20	Yonggang Xie 谢永刚 (KingSemi): (INVITED) Localized Track is capable of advance Process
16:20-16:40	Yiming Zhu (HLMC): Domestic clean track development and improvement for advance node production
16:40-17:00	Closing Plenary Address 闭幕致辞

<u>Day 2:</u>	
<u>6 Nov., 2020 (Friday) — Parallel Session II, 并行报告会场 II</u>	
Shuyun Hall Part B, 蜀韵厅 B	
DAY 2–Morning	
08:30-09:50	Metrology and Inspection Session II Chair: Wei Yuan
	<i>5 minutes Q&A for each talk</i>
08:30-09:00	Gary Zhang (ASML HMI): (INVITED, Online) Enabling Holistic Patterning Applications with High Speed E-beam Metrology and Inspection
09:00-09:30	Bo Hua (KLA): (INVITED) Broadband Plasma Optical Wafer Defect Inspection for Mask Qualification
09:30-09:50	Yunsheng Xia (CXMT 长鑫存储): OPO Measurement Improvement in Advanced DRAM with Tunable Wavelength Imaging
09:50-10:20	Coffee Break
10:20-12:00	Optical Lithography Session Chair: Vincent Chen
	<i>5 minutes Q&A for each talk</i>
10:20-10:50	Wei Yuan (ICRD):

	(INVITED) Machine Learning Hotspot Prediction Significantly Helps to Increase Capture Rate on Wafer
10:50-11:20	Qian Xie (Mentor): (INVITED, Online) Reducing Systematic Defects using Calibre Wafer Defect Management and Machine Learning Solutions
11:20-11:40	Xuelong Shi (ICRD): An effective method of contour extraction for SEM image based on DCNN
11:40-12:00	Zengzhi Huang (CUMEC): The Preliminary Rounds of OPC Development in 180nm node Silicon Photonics MPW platform
12:00-13:30	Lunch
DAY 2-Afternoon	
13:30-15:00	Advanced Material Session II Chair: Mark Neisser
	<i>5 minutes Q&A for each talk</i>
13:30-14:00	Takanori KAWAKAMI (JSR): (INVITED, Online) Advanced Lithography Material Status toward 5nm Node and beyond
14:00-14:20	Sams Hsu (PiBond): New silicon-based materials for semiconductor manufacturing processes
14:20-14:40	Garry Wang (3M): 3M Immobilized Micro-Bed Ion Exchange Resin Bed Technology Treatment of PGMEA
14:40-15:00	TORU FUJIMORI (FUJIFILM): (Online) How to reduce the stochastic issue in EUV lithography
15:00-15:20	Coffee Break
15:20-17:10	New Patterning Process Session Chair: Yayi Wei
	<i>5 minutes Q&A for each talk</i>
15:20-15:50	Eberhard Manske (Technische Universität Ilmenau): (INVITED, Online) Alternative tip- and laser- based nanofabrication

	up to 100 nm on flat and non-flat surfaces with subnanometre precision
15:50-16:20	Qi-Huo Wei (Southern University of Science and Technology 南方科技大学): (INVITED) Photopatterning Molecular Orientations with Plasmonic Metamasks
16:20-16:50	Shisheng Xiong (Fudan University): (INVITED) Sub-10 nm high-resolution patterning combining directed self-assembly of block copolymer and double patterning
16:50-17:10	Gaofeng Liang (Chongqing University): Designing of multilayers for evanescent wave-based interference lithography
17:10-17:20	Closing Plenary Address 闭幕致辞

Poster Session	
5 Nov., 2020 (Thursday) 17:05-18:30 Outdoor of Shuyun Hall 蜀韵厅走廊	
IWAPS2020-P-01	Yu Chen, Shisheng Xiong (Fudan University) Directed self-assembly of block copolymer for fabricating high-density nanowire arrays
IWAPS2020-P-02	Chengyang Hou, Wenzhe Yao, Wei Liu, Yiqin Chen, Huigao Duan, Jie Liu (Hunan University) Ultrafast and Accurate Proximity Effect Correction of Large-Scale Electron Beam Lithography based on FMM and SaaS
IWAPS2020-P-11	Zinan Zhang, Sikun Li, Xiangzhao Wang, Wei Cheng, Shaobo Hu, Zhen Liu (SIOM, CAS) Shadowing Effect Calibration using Neural Network for EUV Lithography
IWAPS2020-P-12	Guodong Chen, Sikun Li, Xiangzhao Wang, Yuguang Chen, Xinhua Yang (SIOM, CAS) A Particle-Collision-Based Etch Model
IWAPS2020-P-13	Weimei Xie, Yanpeng Chen, Shirui Yu, Yu Zhang (HLMC) Evaluating the process performances of binary, PSM and OMOG masks in 14nm technology node
IWAPS2020-	Wei QI, Jing LI, Jinxin CHEN, Xianghong MA (IMECAS)

P-14	A simulation study on measurement frame design based on multi-variable and multi-objective optimization
IWAPS2020-P-15	Chao Fang, Jinyu Qiu, Pandeng Xuan, Yaobin Feng, Lingyi Guo, Jiahui He, Gang Xu, Jin Zhu, Jincheng Pei (YMTC & KLA) Novel target design for thick resist layers overlay measurement improvement
IWAPS2020-P-16	Jiaxin Lin, Lisong Dong, Xu Ma, Taian Fan, Rui Chen, Yayi Wei (IMECAS & BIT) Fast mask near-field calculation using fully convolution network
IWAPS2020-P-17	Pengjie Kong, Lisong Dong, Yayi Wei (IMECAS) An application of chebyshev spectral method in the diffusion of the acid during PEB process
IWAPS2020-P-18	Yang Liu, Yanqiu Li, Lihui Liu, Yiyu Sun, Pengzhi Wei, Enze Li (BIT) Source Optimization under Thick Mask Model
IWAPS2020-P-19	Le MA, Libin ZHANG, Liwan YUE, Zhibiao MAO, Yayi WEI (IMECAS & NATA) Investigation of A New Method to Weigh the Data Used for OPC Model Calibration
IWAPS2020-P-22	Peipei Tao, Li Sheng, Qianqian Wang, Hao Cui, Xiaolin Wang, Xiangming He, Hong Xu (Tsinghua University) Photoresist for Extreme Ultraviolet Lithography
IWAPS2020-P-25	Min Wang, Gabriel Ohlsson (Biolin Scientific AB) Using QCM-D For Analysis Of Surface Interactions Affecting CMP
IWAPS2020-P-26	Jiali Huo, Ying Zhao, Weixing Huang, Fan Zhang, Qiang Huo, Weizhuo Gan, Zhenhua Wu, Huaxiang Yin (IMECAS) Device-Circuit Co-Optimization for Negative Capacitance FinFETs based on SPICE Model
IWAPS2020-P-27	Junwu Wang, S. Zakharov Vassily, Xinbing Wang, Duluo Zuo (Huazhong University of Science and Technology / Russian Academy of Sciences) Experimental Study and Simulation of Extreme Ultraviolet Emission in Laser Induced Discharge Plasma
IWAPS2020-P-31	Yuyang Bian, XiJun Guan, Biqu Liu, Xiaobo Guo, Cong Zhang, Jun Huang, Yu Zhang (HLMC) Pattern Roughness Analyses in Advanced Lithography: Power Spectral Density and Autocorrelation

IWAPS2020-P-32	Yan Yan, Xuelong Shi, Tao Zhou, Bowen Xu, Chen Li, Yifei Lu, Ying Gao (ICRD) Machine Learning Virtual SEM Metrology
IWAPS2020-P-33	Jing LI, Guanghua YANG, Minxia DING, Qingyang ZHANG (IMECAS) Investigation of the relationship between segmented grating mark structure and the diffraction efficiency
IWAPS2020-P-34	Zengxiong LU, Mengnan XU, Yuejing QI, Jing LI (IMECAS) The Polarization tracing in Self-Referencing Interferometer for Displacement Measurement
IWAPS2020-P-35	Libin Zhang, Cong Lu, Yaobin Feng, Yayi Wei (IMECAS & YMTC) Overlay mark sub structure design to improve the contrast
IWAPS2020-P-36	Zhipeng WU, Jing LI, Dongdong XIE, Minxia DING (IMECAS) Modified Anti-windup Control for High Precision Motion System
IWAPS2020-P-37	Jinxin Chen, Minxia Ding, Penghui Wang, Shidong Zhu (IMECAS) Simulation Investigation on Rarefied Gas Flow in Vacuum Chamber
IWAPS2020-P-38	Jos Donders, Anthony Keen, Mohamed Noorani, Niall Walsh, Amedeo Bellunato, Rene Heijink, David Engerran (Edwards) Edwards Contribution to future EUV Lithography scaling

Agenda is subject to change

For update agenda and further information, please visit the website: www.iwaps.org

Locations

